Docket No.

TRANSMITTAL OF FORMAL DRAWINGS

FIS920030375US1 (17192)

In Re Application Of: Huajie Chen, et al

Serial No.	Filing Date	Confirmation No.	Examiner	Art Unit
10/709,239	April 23, 2004	Unassigned	Unassigned	Unassigned

STRUCTURES AND METHODS FOR MANUFACTURING OF DISLOCATION FREE STRESSED CHANNELS IN BULK SILICON AND SOI MOS DEVICES BY GATE STRESS ENGINEERING Invention: VITH SiGe AND/OR Si:C



Address to:

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Transmitted herewith are:

9 sheets of formal drawing(s) for this application.

X Each sheet of drawing indicates the identifying indicia suggested in 37 CFR Section 1.84(c).

William C. Roch

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June 15, 2004 Dated:

I certify that this document and attached formal drawings 6/15/04 with the are being deposited on U.S. Postal Service as first class mail under 37 C.F.R. 1.8 and addressed to the Commissioner for Patents, P.O. Box

1450, Alexandria, VA 22313-1450.

Signature of Person Mailing Correspondence

William C. Roch

Typed or Printed Name of Person Mailing Correspondence